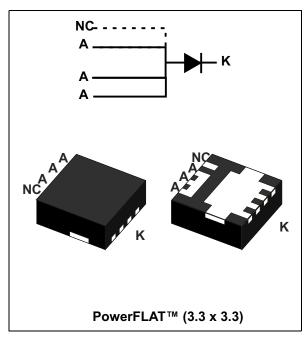


STPS8H100DEE

High voltage power Schottky rectifier

Datasheet - production data



Features

- Very low conduction losses
- Negligible switching losses
- Extremely fast switching
- Low thermal resistance
- Avalanche capacity specified
- High junction temperature
- ECOPACK[®]2 compliant component

Description

This Schottky rectifier is designed for switch mode power supply and high frequency DC to DC converters.

Packaged in PowerFLAT[™], this device is intended for use in low voltage, high frequency, inverters, free-wheeling, bypass diode and polarity protection applications. Its low profile was especially designed to be used in applications with space-saving constraints.

Symbol	Value
I _{F(AV)}	8 A
V _{RRM}	100 V
T _j (max)	175 °C
V _F (typ)	0.68 V

Table 1. Device summary

TM: PowerFLAT is a trademark of STMicroelectronics

DocID023272 Rev 3

1 Characteristics

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	100	V	
I _{F(RMS)}	Forward rms current	15	А	
I _{F(AV)}	Average forward current, δ = 0.5 Tc = 150 °C		8	А
I _{FSM}	Surge non repetitive forward current t _p = 10 ms sinusoidal		100	А
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power $t_p = 10 \ \mu s \ T_j = 125 \ ^{\circ}C$		480	W
T _{stg}	Storage temperature range	-65 to +175	°C	
Тj	Maximum operating junction temperat	175	°C	

 For pulse time duration deratings, please refer to *Figure 3*. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the STMicroelectronics application notes AN1768, "Admissible avalanche power of Schottky diodes" and AN2025, "Converter improvement using Schottky rectifier avalanche specification".

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	4	°C/W

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-		4.5	μA
'R` ′		T _j = 125 °C	VR − VRRM	-	2	6	mA
	Forward voltage drop	T _j = 25 °C	I _F = 8 A			0.82	- V
		T _j = 125 °C		-	0.60	0.68	
V _F ⁽²⁾		T _j = 25 °C	I _F = 10 A			0.85	
VF ⁽⁻⁾		T _j = 125 °C		-	0.62	0.70	
		T _j = 25 °C	I _F = 16 A			0.90	
		T _j = 125 °C		-	0.68	0.75	

Table 4. Static electrical characteristics

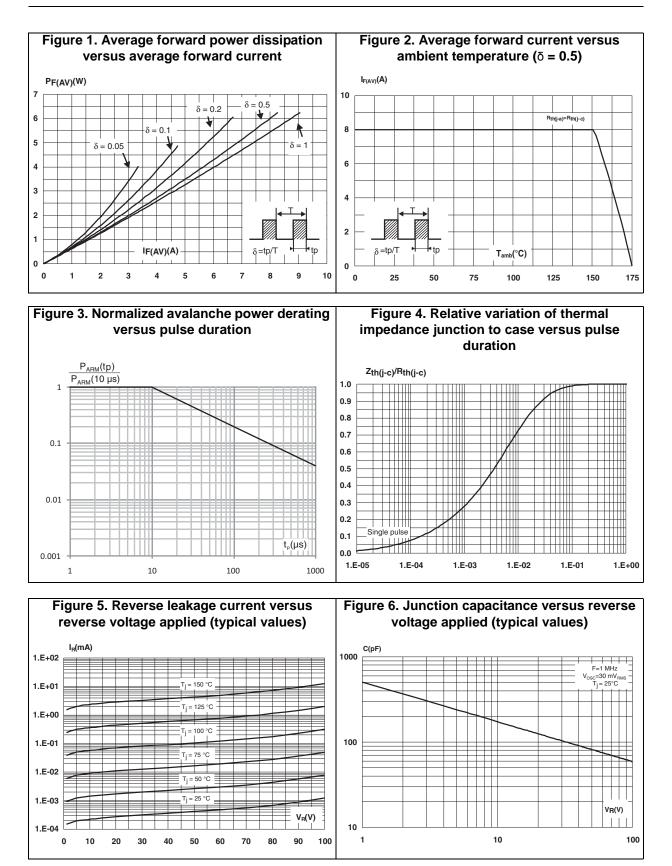
1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: t_p = 380 µs, δ < 2%

To evaluate the conduction losses use the following equation:

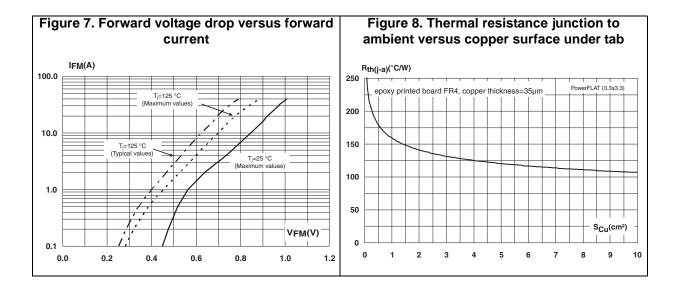
 $P = 0.61 \text{ x } I_{F(AV)} + 0.0088 \text{ x } I_{F}^{2}_{(RMS)}$







DocID023272 Rev 3



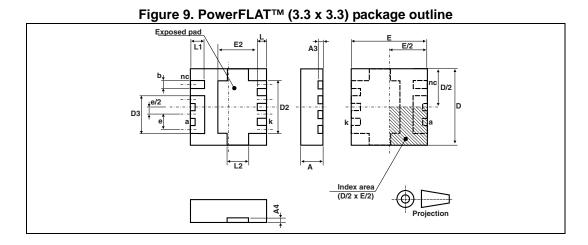


2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.

2.1 PowerFLAT[™] (3.3x3.3)package information

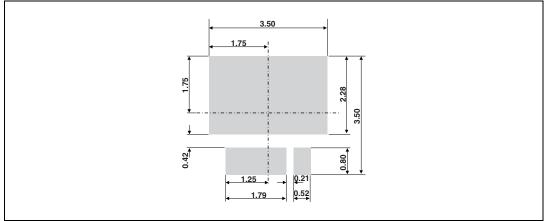




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	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.95	1.00	1.05	0.037	0.039	0.041
A3		0.20			0.0079	
A4		0.20			0.0079	
b	0.30	0.37	0.44	0.012	0.015	0.017
D	3.20	3.30	3.40	0.126	0.130	0.134
D2	2.24	2.31	2.38	0.088	0.091	0.094
D3	1.60	1.67	1.74	0.063	0.066	0.069
е		0.65			0.026	
Е	3.20	3.30	3.40	0.126	0.130	0.134
E2	1.68	1.75	1.82	0.066	0.069	0.072
L	0.31	0.38	0.45	0.012	0.015	0.018
L1	0.55	0.62	0.69	0.22	0.024	0.027
L2	0.86	0.93	1.00	0.034	0.037	0.039

Table 5. PowerFLAT[™] (3.3 x 3.3) mechanical data

Figure 10. Footprint (dimensions in mm)





3 Ordering information

Table 6.	Ordering	information
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Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS8H100DEE-TR	S8H100	PowerFLAT™ (3.3 x 3.3)	34 mg	3000	Tape and reel 13" reel

4 Revision history

Table 7. Document revision history

16-Jan-2015 2 L s		Revision	Changes
		1	First issue.
		2	Updated order code name and reformatted to current standard.
		3	Updated restriction and order code.



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